

Features :

- Interdigitated amplifying gates
- Fast turn-on and high di/dt
- Low switching losses
- Short turn-off time
- Hermetic metal cases with ceramic insulators

$I_{T(AV)}$ **770A**
 V_{DRM}/V_{RRM} **1100~1400V**
 t_q **12~24μs**
 I_{TSM} **9.3kA**

Typical Applications

- Inductive heating
- Electronic welders
- Self-commutated inverters
- AC motor speed control
- General power switching applications



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j(^{\circ}C)$	VALUE			UNIT	
				Min	Type	Max		
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Double side cooled,	125			770	A	
V_{DRM} V_{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	tp=10ms	125	1100		1400	V	
I_{DRM} I_{RRM}	Repetitive peak off-state current Repetitive peak reverse current	at V_{DRM} at V_{RRM}	125			40	mA	
$I_{T(f)}$	High frequency on-state current	$F=6KHz, T_c=55^{\circ}C$				600	A	
I_{TSM}	Surge on-state current	10ms half sine wave	125			9.3	kA	
I^2t	I^2t for fusing coordination	$V_R=0.6V_{RRM}$				432	$A^2 \cdot 10^3$	
V_{TO}	Threshold voltage		125			1.50	V	
r_T	On-state slope resistance					0.58	$m\Omega$	
V_{TM}	Peak on-state voltage	$I_{TM}=1200A, F=15kN$	125			2.20	V	
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125			200	$V/\mu s$	
di/dt	Critical rate of rise of on-state current	$V_{DM}= 67\% V_{DRM}$ to 1200A Gate pulse $t_r \leq 0.5\mu s$ $I_{GM}=1.5A$	125			1500	$A/\mu s$	
Q_{rr}	Recovery charge	$I_{TM}=1000A, tp=2000\mu s,$ $di/dt=-60A/\mu s, V_R=50V$	125		33		μC	
t_q	Circuit commutated turn-off time	$I_{TM}=1000A, tp=2000\mu s, V_R = 50V$ $dv/dt=30V/\mu s, di/dt=-60A/\mu s$	125	12		24	μs	
I_{GT}	Gate trigger current		25	30		250	mA	
V_{GT}	Gate trigger voltage	$V_A=12V, I_A=1A$		0.8		3.0	V	
I_H	Holding current			20		400	mA	
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\% V_{DRM}$	125	0.3			V	
$R_{th(j-c)}$	Thermal resistance Junction to case	DC double side cooled Clamping force 15kN				0.035	$^{\circ}C/W$	
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.008		
F_m	Mounting force			10		20	kN	
T_{stg}	Stored temperature			-40		140	$^{\circ}C$	
W_t	Weight				240		g	
Outline		P08						

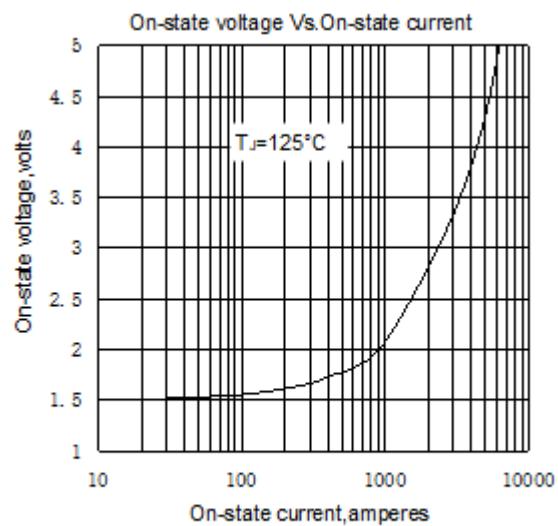


Fig. 1

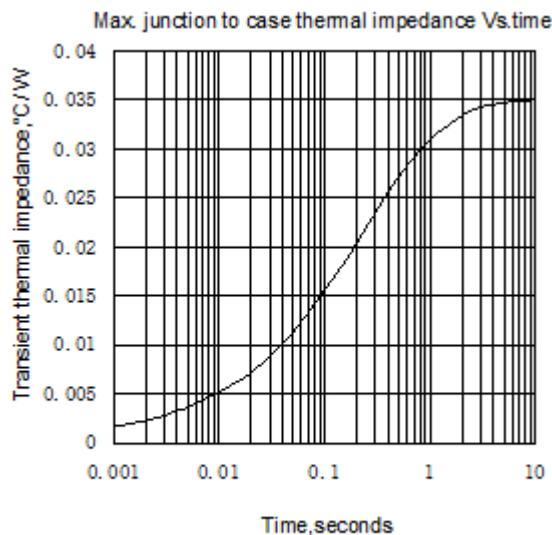


Fig. 2

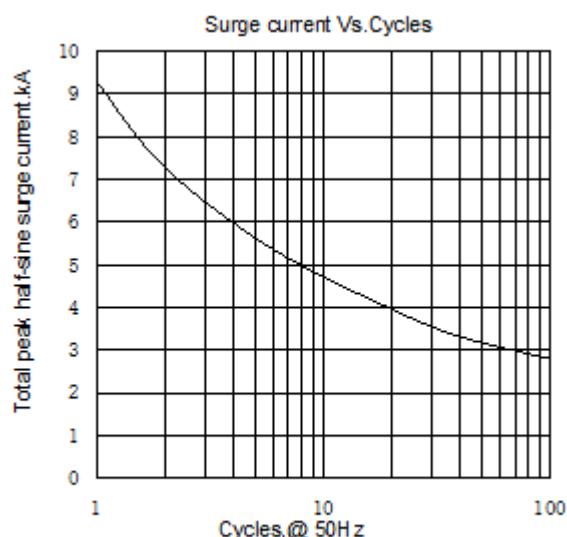


Fig. 3

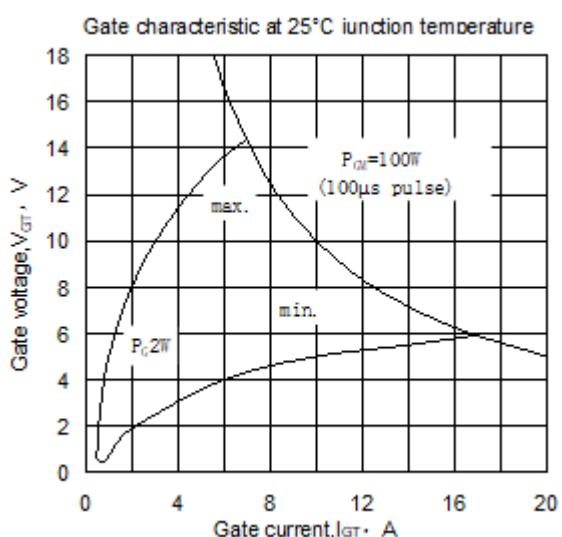


Fig. 4

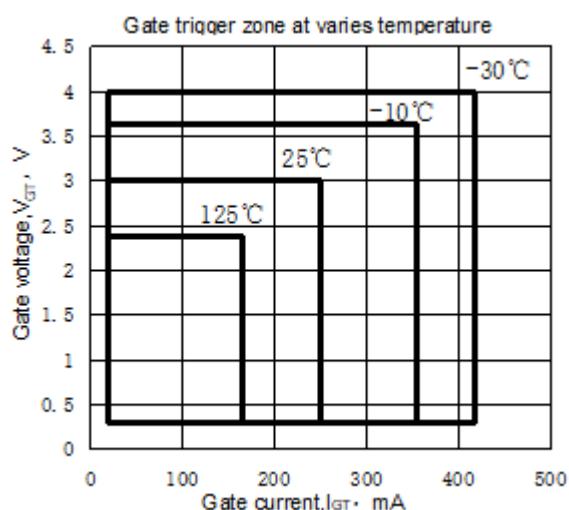


Fig. 5

